

Duration: 3 hours

Maximum Marks: 80

N.B.: (1) Question No. 1 is compulsory.

(2) Solve any **three** questions from the **remaining five**.

(3) Figures to the right indicate full marks.

(4) Assume suitable data if necessary and mention the same in answer sheet.

Q.1 Attempt any 5 questions

[20]

- a) Write down current equation of diode and explain significance of each parameter.
- b) Calculate I_B , I_C and V_{CE} for the common emitter circuit shown in Fig. 1b

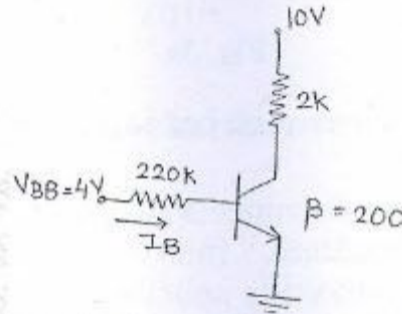


Fig. 1b

- c) Explain effect of temperature on JFET and derive equation for zero temperature drift.
- d) Compare CE, CB and CC configuration.
- e) Draw small signal hybrid pi model of BJT including early effect.
- f) Why LC oscillators are preferred for high frequency applications?

Q.2 a) Draw the output waveform for the clipper and clamper circuit shown in Fig 2a and 2b.

[10]

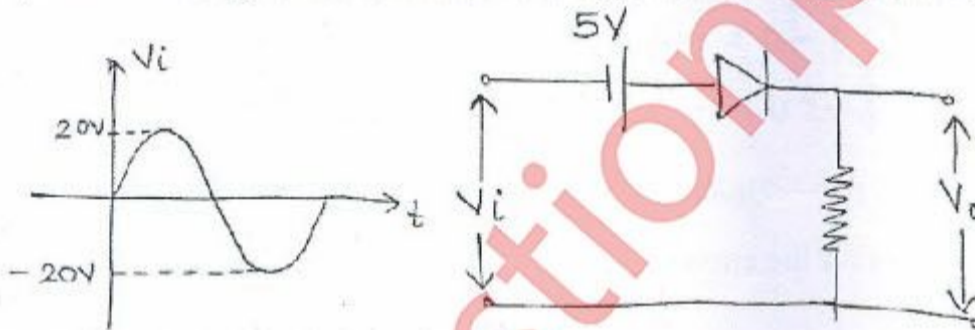


Fig. 2a

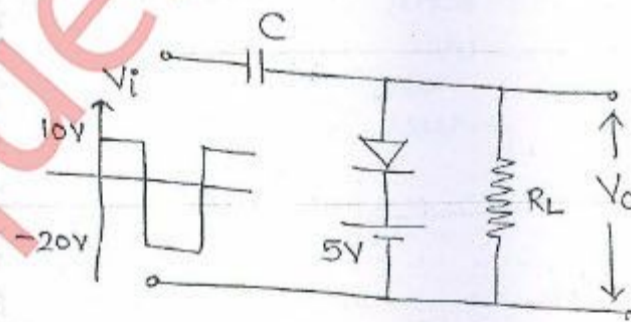


Fig. 2b

b) Derive the expression for frequency of oscillation for a transistorized (BJT) RC phase shift oscillator. [10]

Q.3 a) Find I_{CQ} and V_{CEQ} for the circuit shown in Fig 3a if $\beta = 100$. [10]

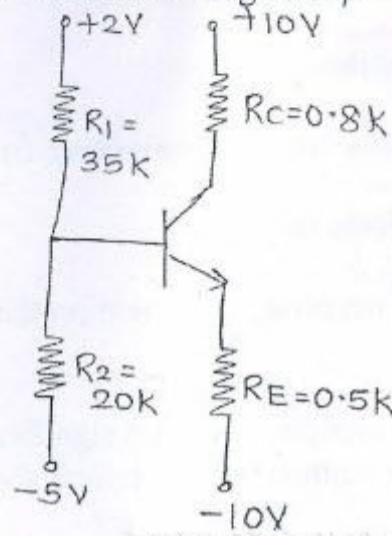


Fig. 3a

b) Explain the construction and characteristics of N-channel Enhancement MOSFET. Draw transfer and drain characteristics. [10]

Q.4 a) For the circuit shown in Fig, 4a, determine V_{GSQ} and V_{DSQ} . Also calculate voltage gain, input impedance and output impedance. [10]

$V_{TN} = 1V, K_N = 0.5 \text{ mA/V}^2, \lambda = 0.01 \text{ V}^{-1}$.

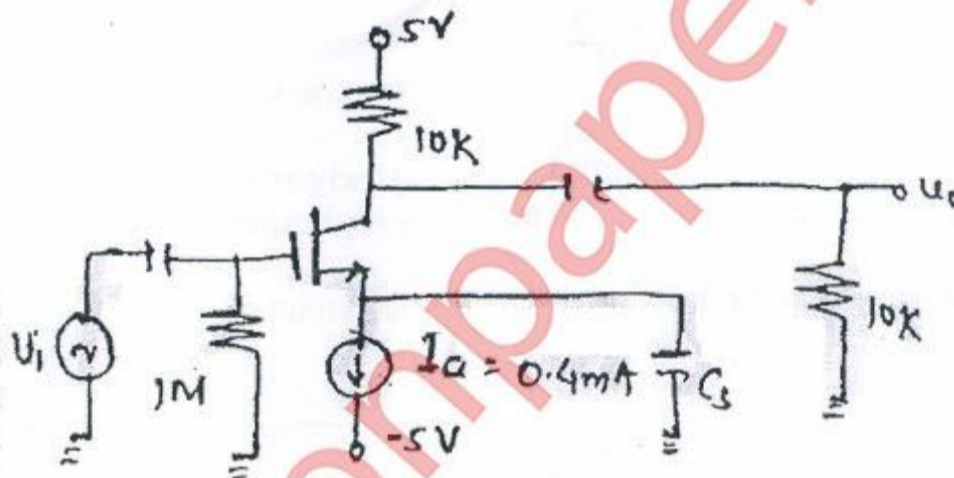


Fig.4a

b) Find $I_{DQ}, V_{GSQ}, V_{DSQ}, V_D$ and V_S for the circuit shown in Fig 4b. [10]

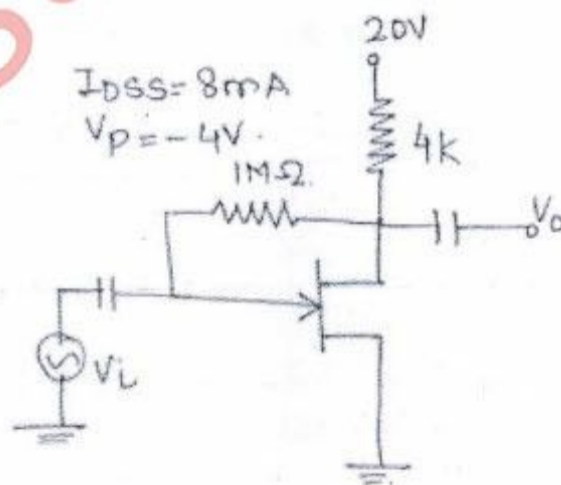


Fig. 4b

- Q.5 a) For the circuit shown below in Fig.5b, the transistor parameters are $V_{BE(on)} = 0.7\text{ V}$, $\beta = 100$ and $V_A = \infty$. Determine Z_i , Z_o and A_v [10]

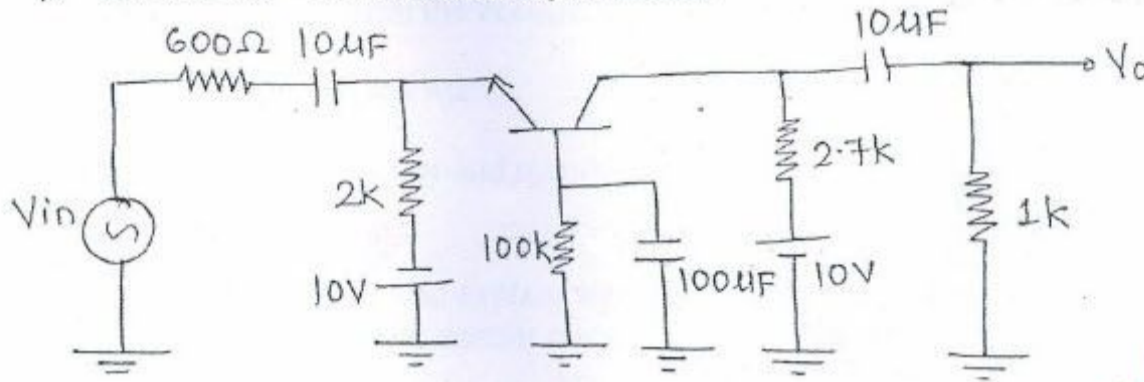


Fig. 5a

- b) Draw and explain energy band diagram of MOS capacitor in accumulation, depletion and inversion region. [10]

- Q.6 Short notes on: (Attempt any four) [20]
- Construction and operation of varactor diode
 - Crystal oscillator
 - Transistor as a switch
 - Emitter follower.
 - Regions of operation of FET